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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	24MHz
Connectivity	I ² C, IrDA, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I ² S, POR, PWM, WDT
Number of I/O	17
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.98V ~ 3.8V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	24-VQFN Exposed Pad
Supplier Device Package	24-QFN (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32zg108f8-qfn24t

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1 Ordering Information

Table 1.1 (p. 2) shows the available EFM32ZG108 devices.

Table 1.1. Ordering Information

Ordering Code	Flash (kB)	RAM (kB)	Max Speed (MHz)	Supply Voltage (V)	Temperature (⁰C)	Package
EFM32ZG108F4-QFN24	4	2	24	1.98 - 3.8	-40 - 85	QFN24
EFM32ZG108F8-QFN24	8	2	24	1.98 - 3.8	-40 - 85	QFN24
EFM32ZG108F16-QFN24	16	4	24	1.98 - 3.8	-40 - 85	QFN24
EFM32ZG108F32-QFN24	32	4	24	1.98 - 3.8	-40 - 85	QFN24

Visit **www.silabs.com** for information on global distributors and representatives.

2.1.12 Pre-Programmed UART Bootloader

The bootloader presented in application note AN0003 is pre-programmed in the device at factory. Autobaud and destructive write are supported. The autobaud feature, interface and commands are described further in the application note.

2.1.13 Low Energy Universal Asynchronous Receiver/Transmitter (LEUART)

The unique LEUARTTM, the Low Energy UART, is a UART that allows two-way UART communication on a strict power budget. Only a 32.768 kHz clock is needed to allow UART communication up to 9600 baud/s. The LEUART includes all necessary hardware support to make asynchronous serial communication possible with minimum of software intervention and energy consumption.

2.1.14 Timer/Counter (TIMER)

The 16-bit general purpose Timer has 3 compare/capture channels for input capture and compare/Pulse-Width Modulation (PWM) output.

2.1.15 Real Time Counter (RTC)

The Real Time Counter (RTC) contains a 24-bit counter and is clocked either by a 32.768 kHz crystal oscillator, or a 32.768 kHz RC oscillator. In addition to energy modes EM0 and EM1, the RTC is also available in EM2. This makes it ideal for keeping track of time since the RTC is enabled in EM2 where most of the device is powered down.

2.1.16 Pulse Counter (PCNT)

The Pulse Counter (PCNT) can be used for counting pulses on a single input or to decode quadrature encoded inputs. It runs off either the internal LFACLK or the PCNTn_S0IN pin as external clock source. The module may operate in energy mode EM0 - EM3.

2.1.17 Analog Comparator (ACMP)

The Analog Comparator is used to compare the voltage of two analog inputs, with a digital output indicating which input voltage is higher. Inputs can either be one of the selectable internal references or from external pins. Response time and thereby also the current consumption can be configured by altering the current supply to the comparator.

2.1.18 Voltage Comparator (VCMP)

The Voltage Supply Comparator is used to monitor the supply voltage from software. An interrupt can be generated when the supply falls below or rises above a programmable threshold. Response time and thereby also the current consumption can be configured by altering the current supply to the comparator.

2.1.19 General Purpose Input/Output (GPIO)

In the EFM32ZG108, there are 17 General Purpose Input/Output (GPIO) pins, which are divided into ports with up to 16 pins each. These pins can individually be configured as either an output or input. More advanced configurations like open-drain, filtering and drive strength can also be configured individually for the pins. The GPIO pins can also be overridden by peripheral pin connections, like Timer PWM outputs or USART communication, which can be routed to several locations on the device. The GPIO supports up to 11 asynchronous external pin interrupts, which enables interrupts from any pin on the device. Also, the input value of a pin can be routed through the Peripheral Reflex System to other peripherals.

3.4.1 EM0 Current Consumption

Figure 3.1. EM0 Current consumption while executing prime number calculation code from flash with HFRCO running at 24 MHz



Figure 3.2. EM0 Current consumption while executing prime number calculation code from flash with HFRCO running at 21 MHz





Figure 3.5. EM0 Current consumption while executing prime number calculation code from flash with HFRCO running at 6.6 MHz



3.4.2 EM1 Current Consumption

Figure 3.6. EM1 Current consumption with all peripheral clocks disabled and HFRCO running at 24 MHz



Figure 3.7. EM1 Current consumption with all peripheral clocks disabled and HFRCO running at 21 MHz



Figure 3.8. EM1 Current consumption with all peripheral clocks disabled and HFRCO running at 14 MHz



Table 3.5. Power Management

Symbol	Parameter	Condition	Min	Тур	Max	Unit
V _{BODextthr} -	BOD threshold on falling external sup- ply voltage		1.74		1.96	V
V _{BODextthr+}	BOD threshold on rising external sup- ply voltage			1.85		V
t _{RESET}	Delay from reset is released until program execution starts	Applies to Power-on Reset, Brown-out Reset and pin reset.		163		μs
CDECOUPLE	Voltage regulator decoupling capaci- tor.	X5R capacitor recommended. Apply between DECOUPLE pin and GROUND		1		μF

3.7 Flash

Table 3.6. Flash

Symbol	Parameter	Condition	Min	Тур	Max	Unit
EC _{FLASH}	Flash erase cycles before failure		20000			cycles
		T _{AMB} <150°C	10000			h
RET _{FLASH}	Flash data retention	T _{AMB} <85°C	10			years
		T _{AMB} <70°C	20			years
t _{W_PROG}	Word (32-bit) pro- gramming time		20			μs
t _{P_ERASE}	Page erase time		20	20.4	20.8	ms
t _{D_ERASE}	Device erase time		40	40.8	41.6	ms
I _{ERASE}	Erase current				7 ¹	mA
I _{WRITE}	Write current				7 ¹	mA
V _{FLASH}	Supply voltage dur- ing flash erase and write		1.98		3.8	V

¹Measured at 25°C

3.8 General Purpose Input Output

Table 3.7. GPIO

Symbol	Parameter	Condition	Min	Тур	Max	Unit
V _{IOIL}	Input low voltage				0.30V _{DD}	V
V _{IOIH}	Input high voltage		0.70V _{DD}			V
V _{ЮОН}	Output high volt- age (Production test	Sourcing 0.1 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = LOWEST		0.80V _{DD}		V
	condition = 3.0V, DRIVEMODE = STANDARD)	Sourcing 0.1 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = LOWEST		0.90V _{DD}		V



Symbol	Parameter	Condition	Min	Тур	Max	Unit
		Sourcing 1 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = LOW		0.85V _{DD}		V
		Sourcing 1 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = LOW		0.90V _{DD}		V
		Sourcing 6 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = STANDARD	0.75V _{DD}			V
		Sourcing 6 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = STANDARD	0.85V _{DD}			V
		Sourcing 20 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = HIGH	0.60V _{DD}			V
		Sourcing 20 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = HIGH	0.80V _{DD}			V
		Sinking 0.1 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = LOWEST		0.20V _{DD}		V
	Output low voltage (Production test	Sinking 0.1 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = LOWEST		0.10V _{DD}		V
		Sinking 1 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = LOW		0.10V _{DD}		V
N/		Sinking 1 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = LOW		0.05V _{DD}		V
VIOOL	DRIVEMODE = STANDARD)	Sinking 6 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = STANDARD			0.30V _{DD}	V
		Sinking 6 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = STANDARD			0.20V _{DD}	V
		Sinking 20 mA, V _{DD} =1.98 V, GPIO_Px_CTRL DRIVEMODE = HIGH			0.35V _{DD}	V
		Sinking 20 mA, V _{DD} =3.0 V, GPIO_Px_CTRL DRIVEMODE = HIGH			0.25V _{DD}	V
I _{IOLEAK}	Input leakage cur- rent	High Impedance IO connected to GROUND or Vdd		±0.1	±100	nA
R _{PU}	I/O pin pull-up resis- tor			40		kOhm
R _{PD}	I/O pin pull-down re- sistor			40		kOhm
R _{IOESD}	Internal ESD series resistor			200		Ohm
t _{IOGLITCH}	Pulse width of puls- es to be removed		10		50	ns



Figure 3.18. Typical Low-Level Output Current, 3.8V Supply Voltage



GPIO_Px_CTRL DRIVEMODE = LOWEST



GPIO_Px_CTRL DRIVEMODE = STANDARD



GPIO_Px_CTRL DRIVEMODE = LOW



GPIO_Px_CTRL DRIVEMODE = HIGH



Figure 3.19. Typical High-Level Output Current, 3.8V Supply Voltage



GPIO_Px_CTRL DRIVEMODE = STANDARD

GPIO_Px_CTRL DRIVEMODE = HIGH

3.9.3 LFRCO

Table 3.10. LFRCO

Symbol	Parameter	Condition	Min	Тур	Мах	Unit
f _{LFRCO}	Oscillation frequen- cy , V_{DD} = 3.0 V, T_{AMB} =25°C		31.29	32.768	34.28	kHz
t _{LFRCO}	Startup time not in- cluding software calibration			150		μs
I _{LFRCO}	Current consump- tion			190		nA
TUNESTEP _L . FRCO	Frequency step for LSB change in TUNING value			1.5		%

Figure 3.20. Calibrated LFRCO Frequency vs Temperature and Supply Voltage







Figure 3.25. Calibrated HFRCO 21 MHz Band Frequency vs Supply Voltage and Temperature



3.9.5 AUXHFRCO

Table 3.12. AUXHFRCO

Symbol	Parameter	Condition	Min	Тур	Max	Unit
		f _{AUXHFRCO} = 21 MHz	20.37	21.0	21.63	MHz
	Oscillation frequen-	f _{AUXHFRCO} = 14 MHz	13.58	14.0	14.42	MHz
f _{AUXHFRCO}	$cy, V_{DD} = 3.0 V,$	f _{AUXHFRCO} = 11 MHz	10.67	11.0	11.33	MHz
	T _{AMB} =25°C	f _{AUXHFRCO} = 6.6 MHz	6.40	6.60	6.80	MHz
		f _{AUXHFRCO} = 1.2 MHz	1.15	1.20	1.25	MHz
t _{AUXHFRCO_settlir}	_g Settling time after start-up	f _{AUXHFRCO} = 14 MHz		0.6		Cycles
TUNESTEP _{AU>} HFRCO	Frequency step for LSB change in TUNING value			0.3		%

3.9.6 ULFRCO

Table 3.13. ULFRCO

Symbol	Parameter	Condition	Min	Тур	Max	Unit
f _{ULFRCO}	Oscillation frequen- cy	25°C, 3V	0.70		1.75	kHz
TC _{ULFRCO}	Temperature coeffi- cient			0.05		%/°C
VC _{ULFRCO}	Supply voltage co- efficient			-18.2		%/V

Figure 3.26. ACMP Characteristics, Vdd = 3V, Temp = 25°C, FULLBIAS = 0, HALFBIAS = 1



Current consumption, HYSTSEL = 4



Response time , V_{cm} = 1.25V, CP+ to CP- = 100mV



3.11 Voltage Comparator (VCMP)

Table 3.15. VCMP

Symbol	Parameter	Condition	Min	Тур	Мах	Unit
V _{VCMPIN}	Input voltage range			V _{DD}		V
V _{VCMPCM}	VCMP Common Mode voltage range			V _{DD}		V
IVCMP	Active current	BIASPROG=0b0000 and HALFBIAS=1 in VCMPn_CTRL register		0.1	0.8	μA
		BIASPROG=0b1111 and HALFBIAS=0 in VCMPn_CTRL register. LPREF=0.		14.7	35	μA
t _{VCMPREF}	Startup time refer- ence generator	NORMAL		10		μs
	Offset voltage	Single ended		10		mV
▼ VCMPOFFSET	Unset voltage	Differential		10		mV
V _{VCMPHYST}	VCMP hysteresis			17		mV
t _{VCMPSTART}	Startup time				10	μs

The V_{DD} trigger level can be configured by setting the TRIGLEVEL field of the VCMP_CTRL register in accordance with the following equation:

VCMP Trigger Level as a Function of Level Setting

V_{DD Trigger Level}=1.667V+0.034 ×TRIGLEVEL

3.12 I2C

Table 3.16. I2C Standard-mode (Sm)

Symbol	Parameter	Min	Тур	Max	Unit
f _{SCL}	SCL clock frequency	0		100 ¹	kHz
t _{LOW}	SCL clock low time	4.7			μs
t _{HIGH}	SCL clock high time	4.0			μs
t _{SU,DAT}	SDA set-up time	250			ns
t _{HD,DAT}	SDA hold time	8		3450 ^{2,3}	ns
t _{SU,STA}	Repeated START condition set-up time	4.7			μs
t _{HD,STA}	(Repeated) START condition hold time	4.0			μs
t _{SU,STO}	STOP condition set-up time	4.0			μs
t _{BUF}	Bus free time between a STOP and START condition	4.7			μs

¹For the minimum HFPERCLK frequency required in Standard-mode, see the I2C chapter in the EFM32ZG Reference Manual. ²The maximum SDA hold time (t_{HD,DAT}) needs to be met only when the device does not stretch the low time of SCL (t_{LOW}).

³When transmitting data, this number is guaranteed only when I2Cn_CLKDIV < ((3450*10⁻⁹ [s] * f_{HFPERCLK} [Hz]) - 5).

(3.2)



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Symbol	Parameter	Condition	Min	Тур	Мах	Unit
I _{GPIO}	GPIO current	GPIO idle current, clock en- abled		5.31		µA/ MHz
I _{PRS}	PRS current	PRS idle current		2.81		µA/ MHz
I _{DMA}	DMA current	Clock enable		8.12		μΑ/ MHz

4 Pinout and Package

Note

Please refer to the application note "AN0002 EFM32 Hardware Design Considerations" for guidelines on designing Printed Circuit Boards (PCB's) for the EFM32ZG108.

4.1 Pinout

The *EFM32ZG108* pinout is shown in Figure 4.1 (p. 37) and Table 4.1 (p. 37). Alternate locations are denoted by "#" followed by the location number (Multiple locations on the same pin are split with "/"). Alternate locations can be configured in the LOCATION bitfield in the *_ROUTE register in the module in question.

Figure 4.1. EFM32ZG108 Pinout (top view, not to scale)



Table 4.1. Device Pinout

	QFN24 Pin# Pin Alternate Functionality / Description and Name								
Pin #	Pin Name	Analog	Timers	Communication	Other				
0	VSS	Ground.							

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Table 4.2. Alternate functionality overview

Alternate		LOCATION							
Functionality	0	1	2	3	4	5	6	Description	
ACMP0_CH0	PC0							Analog comparator ACMP0, channel 0.	
ACMP0_CH1	PC1							Analog comparator ACMP0, channel 1.	
ACMP0_O	PE13		PD6					Analog comparator ACMP0, digital output.	
BOOT_RX	PF1							Bootloader RX.	
BOOT_TX	PF0							Bootloader TX.	
CMU_CLK0			PD7					Clock Management Unit, clock output number 0.	
CMU_CLK1			PE12					Clock Management Unit, clock output number 1.	
								Debug-interface Serial Wire clock input.	
DBG_SWCLK	PF0							Note that this function is enabled to pin out of reset, and has a built-in pull down.	
								Debug-interface Serial Wire data input / output.	
DBG_SWDIO	PF1							Note that this function is enabled to pin out of reset, and has a built-in pull up.	
GPIO_EM4WU0	PA0							Pin can be used to wake the system up from EM4	
GPIO_EM4WU3	PF1							Pin can be used to wake the system up from EM4	
GPIO_EM4WU4	PF2							Pin can be used to wake the system up from EM4	
GPIO_EM4WU5	PE13							Pin can be used to wake the system up from EM4	
HFXTAL_N	PB14							High Frequency Crystal negative pin. Also used as external optional clock input pin.	
HFXTAL_P	PB13							High Frequency Crystal positive pin.	
I2C0_SCL		PD7			PC1	PF1	PE13	I2C0 Serial Clock Line input / output.	
I2C0_SDA	PA0	PD6			PC0	PF0	PE12	I2C0 Serial Data input / output.	
LEU0_RX		PB14		PF1	PA0			LEUART0 Receive input.	
LEU0_TX		PB13		PF0	PF2			LEUART0 Transmit output. Also used as receive input in half duplex communication.	
LFXTAL_N	PB8							Low Frequency Crystal (typically 32.768 kHz) negative pin. Also used as an optional external clock input pin.	
LFXTAL_P	PB7							Low Frequency Crystal (typically 32.768 kHz) positive pin.	
PCNT0_S0IN			PC0	PD6				Pulse Counter PCNT0 input number 0.	
PCNT0_S1IN	PC14		PC1	PD7				Pulse Counter PCNT0 input number 1.	
PRS_CH0	PA0		PC14					Peripheral Reflex System PRS, channel 0.	
PRS_CH1			PC15					Peripheral Reflex System PRS, channel 1.	
PRS_CH2	PC0							Peripheral Reflex System PRS, channel 2.	
PRS_CH3	PC1							Peripheral Reflex System PRS, channel 3.	
TIM0_CC0	PA0	PA0			PA0	PF0		Timer 0 Capture Compare input / output channel 0.	
TIM0_CC1					PC0	PF1		Timer 0 Capture Compare input / output channel 1.	
TIM0_CC2					PC1	PF2		Timer 0 Capture Compare input / output channel 2.	
TIM1_CC0				PB7	PD6			Timer 1 Capture Compare input / output channel 0.	
TIM1_CC1	PC14			PB8	PD7			Timer 1 Capture Compare input / output channel 1.	
TIM1_CC2	PC15	PE12		PB11				Timer 1 Capture Compare input / output channel 2.	
US1_CLK	PB7		PF0	PC15				USART1 clock input / output.	
US1_CS	PB8		PF1	PC14				USART1 chip select input / output.	
US1_RX	PC1		PD6	PD6				USART1 Asynchronous Receive.	

Note:

- 1. Dimensioning & tolerancing confirm to ASME Y14.5M-1994.
- 2. All dimensions are in millimeters. Angles are in degrees.
- 3. Dimension 'b' applies to metallized terminal and is measured between 0.25 mm and 0.30 mm from the terminal tip. Dimension L1 represents terminal full back from package edge up to 0.1 mm is acceptable.
- 4. Coplanarity applies to the exposed heat slug as well as the terminal.
- 5. Radius on terminal is optional

Table 4.4. QFN24 (Dimensions in mm)

Symbol	Α	A1	A3	b	D	E	D2	E2	е	L	L1	aaa	bbb	ссс	ddd	eee
Min	0.80	0.00		0.25			3.50	3.50		0.35	0.00					
Nom	0.85	-	0.203 REF	0.30	5.00 BSC	5.00 BSC	3.60	3.60	0.65 BSC	0.40		0.10	0.10	0.10	0.05	0.08
Max	0.90	0.05		0.35			3.70	3.70		0.45	0.10					

The QFN24 Package uses Nickel-Palladium-Gold preplated leadframe.

All EFM32 packages are RoHS compliant and free of Bromine (Br) and Antimony (Sb).

For additional Quality and Environmental information, please see: http://www.silabs.com/support/quality/pages/default.aspx



Figure 5.2. QFN24 PCB Solder Mask



Table 5.2. QFN24 PCB Solder Mask Dimensions (Dimensions in mm)

Symbol	Dim. (mm)	Symbol	Dim. (mm)
а	0.92	е	5.00
b	0.42	f	3.72
С	0.65	g	3.72
d	5.00	-	-

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